NSN 5961-01-422-4900

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-422-4900 **Inclosure Material:** Plastic and metal **Overall Length:** 0.410 inches **Overall Height:** 0.096 inches **Overall Width:** 0.268 inches **End Application:** Arc-222 **Internal Configuration:** Field effect **Electrode Internally-electrically Connected To Case:** Drain **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -200.0 drain to source voltage and 20.0 gate to source voltage **Power Rating Per Characteristic:** 25.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius ambient air **Test Data Document:** 37695-381509 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:**